

Technical Data

Green Products

Data Sheet N1151, Rev. -

# Power Surface Mount Schottky Rectifier (20V, 60Amp)

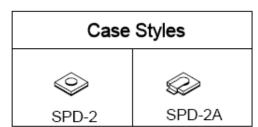
# **Applications:**

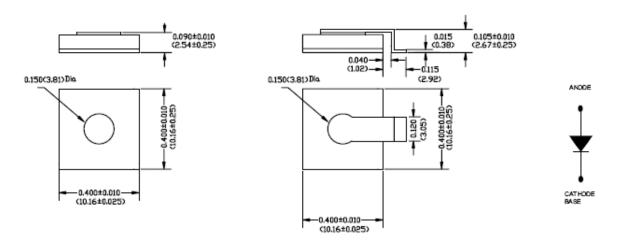
- Switching power supply Redundant power subsystems Reverse battery protection
- Converters Many other high current AC/DC power supplies

#### Features:

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Mechanical Dimensions: In Inches / mm





SPD-2 SPD-2A

# Suffix "R" Denotes Reversed Polarity

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# **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	20	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle, rectangular wave form	60	Α
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	860	А
Non-Repetitive Avalanche Energy	E <sub>AS</sub>	T <sub>J</sub> =25℃,I <sub>AS</sub> =3.4A,L=6.5mH	37.6	mJ
Repetitive Avalanche Current	I <sub>AR</sub>	Current decaying linearly to zero in 1 µsec Frequency limited by T <sub>J</sub> max. V <sub>A</sub> =1.5×V <sub>R</sub> typical	3.4	Α

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop*	$V_{F1}$	@ 60A, Pulse, T <sub>J</sub> = 25 °C	0.48	V
	$V_{F2}$	@ 60A, Pulse, T <sub>J</sub> = 125 °C	0.35	V
Max. Reverse Current (per	I <sub>R1</sub>	$@V_R = \text{rated } V_R, \text{ Pulse},$	6	mA
leg) *		T <sub>J</sub> = 25 °C		
	$I_{R2}$	$@V_R = rated V_R, Pulse,$	660	mA
		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	$C_J$	$@V_R = 5V, T_C = 25 °C$	4050	pF
(per leg)		f <sub>SIG</sub> = 1MHz		
		Vsig=50mV(p-p)		

<sup>\*</sup> Pulse Width < 300µs, Duty Cycle <2%

# **Thermal-Mechanical Specifications:**

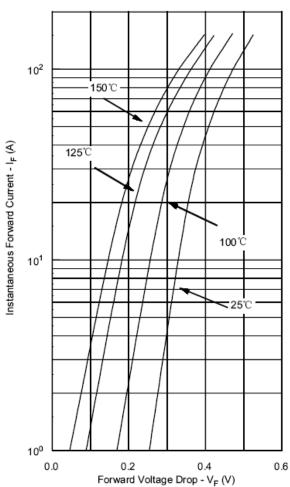
Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$	DC operation	0.37	°C/W
Case Style		SPD-2/A		



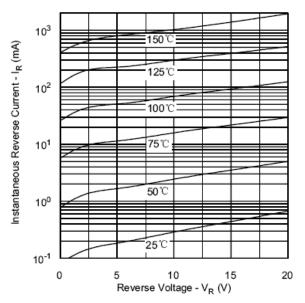


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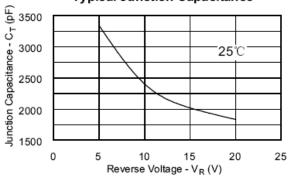
# Typical Forward Characteristics



## Typical Reverse Characteristics



# Typical Junction Capacitance



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